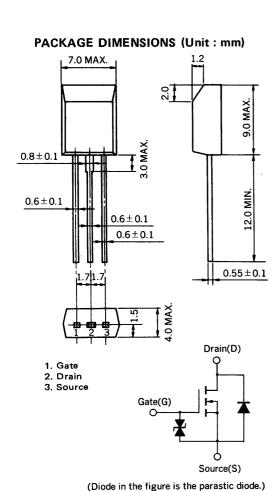
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P1 98.2



MOS FIELD EFFECT TRANSISTOR **2SK1274**

N-CHANNEL MOS FET FOR HIGH SPEED SWITCHING



The 2SK1274, N-channel vertical type MOS FET, is a switching device which can be driven directly by the output of ICs having a 5 V power source.

The MOS FET has excellent switching characteristics and is suitable for use as a high-speed switching device in digital circuits.

FEATURES

- Directly driven by ICs having a 5 V power source.
- Not necessary to consider driving current because of its high input impedance.
- Possible to reduce the number of parts by omitting the bias resistor.
- Low ON-state resistance

 $R_{DS(on)}$ = 1.00 Ω TYP. at V_{GS} = 4 V, I_D = 0.5 A $R_{DS(on)}$ = 0.65 Ω TYP. at V_{GS} = 10 V, I_D = 0.5 A

QUALITY GRADE

Standard

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

ABSOLUTE MAXIMUM RATINGS ($T_a = 25$ °C)

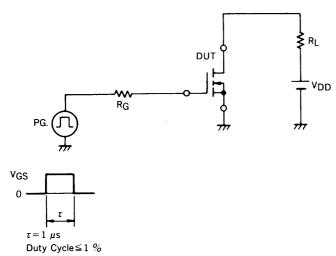
PARAMETER	SYMBOL	RATINGS	UNIT	TEST CONDITIONS
Drain to Source Voltage	V _{DSS}	60	V	V _{GS} = 0
Gate to Source Voltage	V _{GSS}	±20	V	V _{DS} = 0
Drain Current	ID(DC)	±1.5	Α	
Drain Current	ID(pulse)	±3.0	Α	PW ≦ 10 ms, Duty Cycle ≦ 50 %
Total Power Dissipation	PT	1.0	w	
Channel Temperature	T _{ch}	150	°C	
Storage Temperature	T _{stg}	-55 to +150	°C	

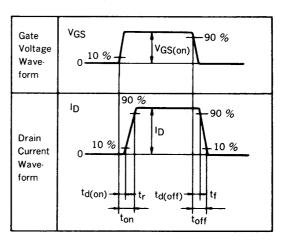


ELECTRICAL CHARACTERISTICS ($T_a = 25$ °C)

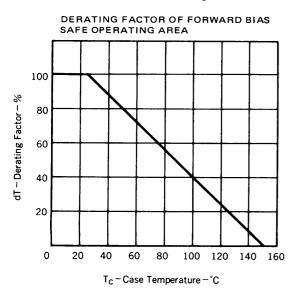
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS	
Drain Cut-off Current	IDSS			10	μА	V _{DS} = 60 V, V _{GS} = 0	
Gate Leakage Current	IGSS			±10	μА	V _{GS} = ±20 V, V _{DS} = 0	
Gate Cut-off Voltage	V _{GS(off)}	1.0	1.7	2.5	V	V _{DS} = 10 V, I _D = 1 mA	
Forward Transfer Admittance	lyfs l	0.4			s	V _{DS} = 10 V, I _D = 0.5 A	
Drain to Source On-State Resistance	R _{DS(on)1}		0.31	1.00	Ω	V _{GS} = 4.0 V, I _D = 0.5 A	
Drain to Source On-State Resistance	R _{DS(on)2}		0.24	0.65	Ω	V _{GS} = 10 V, I _D = 0.5 A	
Input Capacitance	C _{iss}		220		pF	V _{DS} = 10 V, V _{GS} = 0, f = 1 MHz	
Output Capacitance	Coss		105		pF		
Feedback Capacitance	C _{rss}		16		pF		
Turn-On Delay Time	td(on)		15		ns	$V_{GS(on)} = 10 \text{ V}, R_G = 10 \Omega$ $V_{DD} = 25 \text{ V}, I_D = 0.5 \text{ A}$ $R_L = 50 \Omega$	
Rise Time	t _r		35		ns		
Turn-Off Delay Time	^t d(off)		380		ns		
Fall Time	t _f		120		ns		

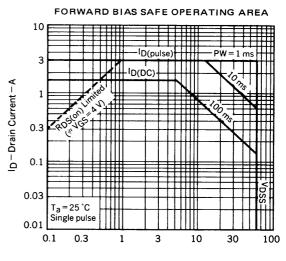
SWITCHING TIME MEASUREMENT CIRCUIT AND CONDITIONS



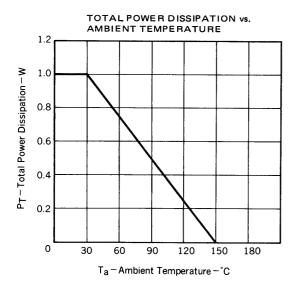


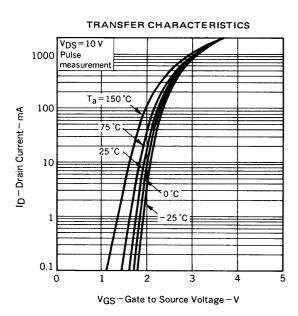
TYPICAL CHARACTERISTICS ($T_a = 25$ °C)

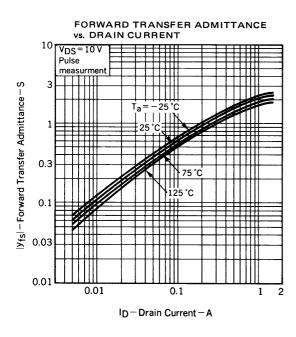


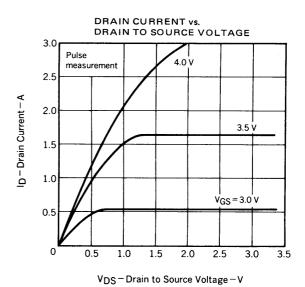


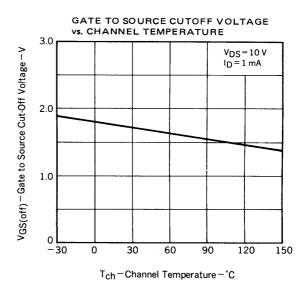
VDS - Drain to Source Voltage - V

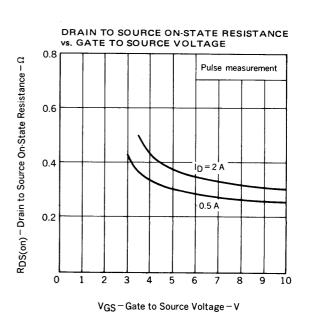


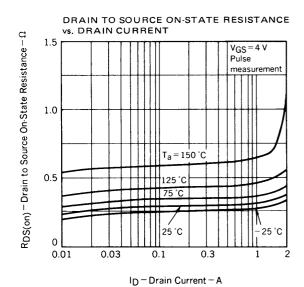


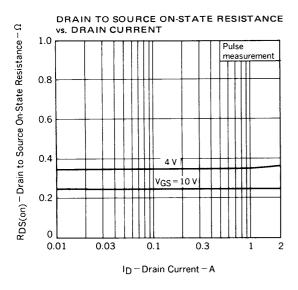


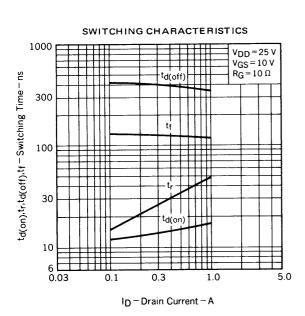


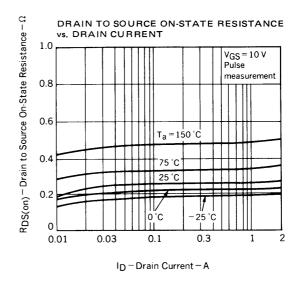


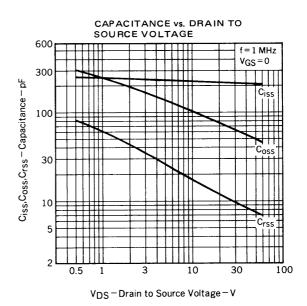


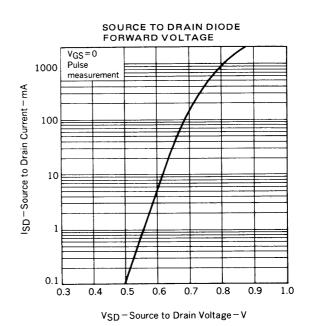












RECOMMENDED SOLDERING CONDITIONS

Solder this product under the following recommended conditions.

For soldering methods or soldering conditions other than those recommended in the table, please consult our NEC salespeople.

Insert type

Soldering method	Soldering conditions	Recommended condition code
Wave soldering	Solder bath temperature: 260 °C max. Soldering time: 10 sec max.	

(MEMO)

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The devices listed in this document are not suitable for use in the field where very high reliability is required including, but not limited to, aerospace equipment, submarine cables, unclear reactor control systems and life support systems. If customers intend to use NEC devices for above applications or those inted to use "Standard", or "Special" quality grade NEC devices for the applications not intended by NEC, please contact our sales people

Application examples recomended by NEC Corporation

Standard: Data processing and office equipment, Communication equipment (terminal, mobile). Test and

Measurement equipment, Audio and Video equipment, Other consumer products, etc.

Special: Automotive and Transportation equipment, Communication equipment (trunk line), Train and

Traffic control devices, industrial robots, Burning control systems, antidisaster systems, anticrime

systems etc.